Impact of Dzyaloshinskii–Moriya interaction and anisotropy on topological Hall effect

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Abstract

Electron transport combined with magnetism has gained more attention to the spintronics community in the last few decades. Among them, the topological Hall effect, which arises due to the emergent magnetic field of a non-trivial object, is found to be a promising tool for probing a skyrmion. A sizeable interfacial Dzyaloshinskii–Moriya interaction (iDMI) with reduced effective anisotropy can stabilize skyrmions in thin films. Recently, a large iDMI has been predicted in Pt/Co/Re thin film. Thus, we have studied the effect of iDMI and anisotropy on the topological Hall effect (THE) in perpendicularly magnetized Pt/Co/X (X=Ta, Re) thin films. The presence of skyrmions is confirmed via THE as well as magnetic force microscope (MFM) imaging. Two different natures of THE signals have been explained in the two different types of samples via micromagnetic simulations. It has been found that effective anisotropy and DMI interaction contribute significantly to decide the different topological Hall behavior.

Introduction

Magnetic skyrmions are non-collinear, swirling, chiral topological spin textures. In the last few decades, skyrmions have attracted great research interest to the spintronics community due to their unique topological property, high thermal stability, nanoscale size, and low driving critical current density.^{1,2} It has been predicted that skyrmions are a very promising candidate for enhancing next-generation data storage density, racetrack memory, logic devices, transistor-like devices, neuromorphic computing, etc.^{2–5} Skyrmions stabilize in a thin film through a complicated interplay of exchange interaction, magnetic anisotropy, interfacial Dzyaloshinskii-Moriya interaction (DMI), dipolar energy, and Zeeman energy.^{3,6–11} However, in specific circumstances, frustrated interaction, four-spin interaction, exchange bias, etc. also play a significant role in the formation of a skyrmion.^{12,13} To meet the requirement of practical applications, skyrmions have been investigated in several ferromagnetic systems, ferromagnetic alloys, ferrimagnets, synthetic antiferromagnets, and recently in 2D materials.^{7,14–17} The interaction of skyrmions with conduction electrons leads to exotic electrodynamics.¹⁸ When a conduction electron moves through a slowly varying exchange field of chiral spin textures i.e., skyrmions, chiral domain walls, etc., the spin of the electron follows spatially varying local magnetization in the adiabatic limit (or strong-coupling limit). From the electron frame of reference, the electron experiences a time-dependent magnetic field due to a non-zero scalar spin chirality $(\chi_{ijk} \sim \mathbf{S}_i \cdot \mathbf{S}_j \times \mathbf{S}_k \neq 0)$ i.e., the solid angle occupied by the non-coplanar magnetization directions which leads to a Berry phase in real space.^{19,20} Now the Berry phase deflects the conduction electron perpendicular to the current flow direction and adds an additional contribution to the Hall signal which is known as the topological Hall effect (THE). THE is a very useful and efficient tool to confirm the existence of chiral texture in a system. First, it was observed in non-centrosymmetric crystalline structures (B20-type bulk materials).²¹ Later, it has been also explored in thin film having iDMI. Heavy metal (HM1)/Ferromagnet (FM)/HM2 is an ideal thin film system for stabilizing skyrmion and studying THE.^{22–24} By choosing a proper combination of HM1 and HM2 across a FM, an additive iDMI can be achieved in a system that gives an additional degree of freedom in stabilizing the skyrmions. Recently, using first-principle calculations, it has been predicted that Pt/Co/Re system possesses a huge iDMI interaction (iDMI constant, $D \sim 9.17 \text{ mJ/m}^2$) than any other thin film system like Pt/Co/W, etc.^{25,26} Further, the experiment proved that Pt and Re induce opposite chirality and the iDMI arising from Pt/Co and Co/Re interface added up.²⁷ The iDMI plays a pivotal role in stabilizing skyrmion which induces the THE in a system. Furthermore, a fine-tuning of domain wall (DW) energy in a system is also very much essential to host the spin textures. A large positive energy collapses the skyrmions whereas a large negative energy causes to destabilization of the colinear order (requires a higher magnetic field to achieve isolated skyrmion). The most efficient way of achieving this is to reduce the effective anisotropy energy of a system near to zero. Therefore, iDMI and anisotropy of a system are very crucial. Previously the effect of DMI and anisotropy has been explored in skyrmion stabilization.²⁸ However, the effect of these factors on THE is less explored.

In this context, we have considered two model systems of Pt/Co/Ta and Pt/Co/Re thin films. It is well known that the Pt/Co interface induces a sizeable iDMI.^{15,29} However, very negligible iDMI (with the same sign as the Co/Pt interface) emerged from the top Co/Ta interface.^{30,31} So, the resulting iDMI in Pt/Co/Ta is expected to be smaller than a single Pt/Co interface.^{30,31} On the contrary, Co/Re exhibits a sizeable iDMI with the opposite sign of the Co/Pt interface. Therefore, in the case of the Pt/Co/Re system both the interface contributes to induce an additive iDMI.^{25–27} Thus, a higher iDMI is expected from the Pt/Co/Re system in comparison to Pt/Co/Ta. As both systems are expected to have different iDMI and anisotropy energies, the impact of these factors on the THE signal is studied in detail. The topological Hall resistivity indicates the presence of skyrmion in the samples which has been confirmed by magnetic force microscopy (MFM) imaging. Further, topological Hall resistivity as a function of field shows different behaviour in two different types of samples. A single peak or deep has been found in the case of the Pt/Co/Ta system. However, in Pt/Co/Re, we have observed simultaneous peaks and deep (or double peaks with opposite signs) in resistivity during the field sweep. For a better understanding of the types of Hall signatures, we have performed micromagnetic simulations. It is observed that DMI interaction and effective anisotropy (K_{eff}) are crucial in defining topological Hall behaviour in a system.



Experimental details

Figure 1: (a) Schematic of the sample structures. (b) Polar MOKE hysteresis loops of the samples S1-S3.

Three samples Ta(5)/Pt(6)/Co(1.5)/Ta(4), Ta(5)/Pt(6)/Co(1.4)/Re(3.5)/Ta(4) and Ta(5)/Pt(6)/Co(1.5)/Re(3.5)/Ta(4) have been prepared on 100 nm thermally oxidized Si substrates and named as S1, S2 and S3, respectively. The numbers in the parenthesis indicate the thicknesses of respective layers in nm. A schematic representation of the sample structure is shown in Figure 1 (a). DC magnetron sputtering has been used to deposit the Ta, Pt, and Co layers, whereas RF magnetron sputtering has been used to prepare the Re layer with a base pressure $\sim 8 \times 10^{-8}$ mbar. The substrate table has been rotated at 10 rpm during the deposition to achieve uniform layers. Magneto optic Kerr effect (MOKE) based microscopy has been used to measure the hysteresis behaviour of the samples. The saturation magnetization (M_s) and effective anisotropy (K_{eff}) have been quantified via a superconducting quantum interference device (SQUID) magnetometer. Skyrmion imaging has been performed via MFM using commercially purchased magnetic tips (Nanosensor, SSS-MFMR). The topological Hall Effect measurements have been performed via a physical property measurement system (PPMS) in the \pm 3T field range in the Van der Pauw geometry. A small AC current density (10⁶ A/m²) has been used for the transport measurements so that the spin textures do not perturb. Micromagnetic simulations have been performed using MUMAX3 software.³² The simulation area was 2 µm × 2 µm. The cell size was 2 × 2 × 1.4 nm³. The values of M_s and K_{eff} used in the simulation are very close to experimentally obtained values. The exchange constant, A = 25 pJ/m has been considered in the simulation. To achieve a realistic response, the simulation area has been split into grains of size 10 nm using random Voronoi tessellation. We have also used periodic boundary conditions (PBC) in the simulations.

Table 1: The values of M_{s,H_s} , and K_{eff} of samples S1-S3 obtained from SQUID measurements.

Sample	$M_s(A/m)$	$\mu_0 H_s(\mathrm{mT})$	$K_{\rm eff}~({\rm MJ/m^3})$
S1	1.63×10^{6}	650	0.53
S2	1.51×10^6	720	0.54
S3	1.53×10^6	600	0.46

Results and discussion

Figure 1(b) shows the polar MOKE hysteresis loops, confirming that the easy axis of all the samples aligns in the out-of-plane direction. Also, the low remanence slanted hysteresis loop indicates the presence of chiral textures in the samples. The M_s values of all the samples are given in table 1 and the corresponding hysteresis loops obtained from SQUID measurement are shown in figure S1(a) of the supplementary information file. Further, the effective anisotropy (K_{eff}) of all the samples has been determined using the relation, $K_{eff} = \frac{1}{2}\mu_0 H_s M_s$ where $\mu_0 H_s$ is the in-plane saturation field (as shown in figure S1 (b-d) in supplementary information). The values of the effective anisotropy constant (K_{eff}) are

listed in table 1.



Figure 2: (a), (c) and (e) AHE+THE and AHE contribution in ρ_{xy} as a function of field for sample S1, S2 and S3, respectively. (b), (d) and (f) Plots of ρ_{THE} vs field for sample S1, S2, and S3 respectively. The black arrow signs represent the field sweep direction.

To confirm the existence of the chiral textures in the samples, THE measurements have been performed. In a FM material, the total Hall resistivity (ρ_{xy}) is the sum of three contributions i.e., ordinary (ρ_{OHE}), anomalous (ρ_{AHE}), and topological (ρ_{THE}) Hall resistivities. The ordinary Hall effect (OHE) is linearly proportional to the applied field. The anomalous Hall effect (AHE) arises due to the time-reversal symmetry breaking in the FM and is linearly proportional to the magnetization. THE originated in a thin film due to the presence of nontrivial spin texture like skyrmions. Therefore, ρ_{xy} can be expressed as,^{20,22,33}

$$\rho_{xy} = \rho_{OHE} + \rho_{AHE} + \rho_{THE} = R_0 H + R_s M(H) + \rho_{THE} \tag{1}$$

where R_0 and R_s are the ordinary and anomalous Hall coefficients and M(H) is the outof-plane magnetization as a function of the applied field (*H*). Thus, ρ_{THE} can be extracted by subtracting the other two components from ρ_{xy} . Now, the OHE contribution has been eliminated from ρ_{xy} by fitting a linear function above 1.5 T, and the remaining (AHE + THE) components as a function of *H* have been shown in figure 2(a), (c) and (e) for the samples S1, S2 and S3, respectively. At higher fields, the AHE contribution gets saturated and the R_s can be deduced as, $R_s = \frac{\rho_{xy,saturation}}{M_s}$.^{33,34} Hence, the AHE components have been determined by scaling the M - H loops with R_s . Now, ρ_{THE} is quantified after subtracting the AHE contributions from the remaining resistivity. The ρ_{THE} as a function of field is shown in figure 2(b), (d), and (f) for samples S1, S2, and S3, respectively. A maximum ρ_{THE} of ~ 0.08, ~ 0.12, and ~ 0.10 n Ω m have been observed for samples S1, S2, and S3, respectively. The topological Hall resistivity confirms the presence of chiral spin textures in the samples. The ρ_{THE} is proportional to the average topological charge or skyrmion number:^{33,35}

$$\rho_{THE} = R_T \left\langle Q_{sk} \right\rangle \tag{2}$$

The average skyrmion number, $\langle Q_{sk} \rangle$, is the sum of the skyrmion numbers, Q_{sk} , of all individual objects present in the sample. The topological Hall coefficient, R_T , represents the density and spin-polarization of the carriers. The Q_{sk} is defined as a product of vorticity (V)and core polarity (P) of the texture i.e. $Q_{sk} = V.P.^{33,36}$ The vorticity, V = +1 for skyrmion. The P defines the orientation of a core magnetic moment along the out-of-plane direction of a texture. The value of it is determined by considering the background magnetization. P =



Figure 3: (a-d) Field-dependent MFM images exhibiting the process of skyrmion formation. The isolated skyrmions are observed at $H_z \ge 12$ mT.

+1 (-1) for a $-M_s$ (+ M_s) magnetized sample. So, depending upon the core polarity, P, (+1 or -1), Q_{sk} could be either +1 or -1 which basically defines two distinct phases of topological objects. It should be noted that during the field sweep from +ve to -ve saturation field (or vice versa), we have observed a single peak in ρ_{THE} for S1 (figure 2 (b)) which signifies only one type of texture. Whereas both a peak and a deep (in the rest of the manuscript we called it as double peak with opposite sign) have been noticed for the samples S2 (figure 2 (d)) and S3 (figure 2 (f)) during the field sweep. Now, a sign change in R_T is only possible by changing the temperature. As all the measurements are performed at room temperature, for double peak, sign change in ρ_{THE} solely depends on Q_{sk} . During the field sweep, the core polarity switches, hence, two distinct textures could be observed in this case (later in the manuscript, we have described in detail).

Additionally, from MFM scanning on S1, it has been found that the chiral textures are skyrmions. At a demagnetized state, a worm-like domain state is observed, as shown in Figure 3 (a). Further, increasing the field the worm-like domains start to contract (figure 3 (b)) and form isolated skyrmions as shown in Figure 3 (c-d). At higher fields, skyrmion density is reduced and finally, a saturated state is achieved. However, in samples S2 and S3, the domains become saturated due to the stray field of the MFM tip, which is the same tip used for sample S1 (MFM images are shown in Figure S2 of the supplementary information). This observation suggests that the samples containing the Re layer (S2 and S3) exhibit a lower pinning landscape than S1 [9].



Figure 4: (a) Plot of $\langle Q_{sk} \rangle$ vs $\mu_0 H$ at a constant K_{eff} obtained from simulations.

Further, the reason behind the different shapes of ρ_{THE} (figure 2(b) and (d)) in samples S1 and S2 (or S3), has also been understood via micromagnetic simulations. Previously, this kind of a single peak ^{37,38} and double peak (i.e., double peak with opposite sign)^{22,23,39,40} in resistivity were observed in different thin films. The emergence of a signal peak can be attributed to the presence of a singular type of topological object. Conversely, the manifestation of double peaks with opposite signs is indicative of the coexistence of two distinct phases (i.e. $Q_{sk} = +1$ and -1) of a topological object [20,21,37,38]. Recently, P. K. sivakumar et al. explained that a double peak (with the same sign) in topological resistivity comes due to the presence of skyrmion and anti-skyrmion having the same topological charge in a MgO (001)/Mn₂RhSn system.³³ However, the precise conditions leading to the occurrence of either a single peak or a double peak (with opposite signs) in the Hall signature have not been thoroughly investigated. Thus, we have investigated the origin of such behaviour in ρ_{THE} via micromagnetic simulations. In our simulations, the magnetization of the system has been changed from +ve to -ve saturation state by varying the applied field with a small step. In every field value the average skyrmion number, $\langle Q_{sk} \rangle$, is calculated using the

'ext – topologicalcharge' command in Mumax3. As iDMI defines the chirality of a system, the iDMI value, D, is varied in a range of 0.5-5.0 mJ/m³ considering $M_s = 1.53 \times 10^6$ A/m and $K_{eff} = 0.4$ MJ/m³. From equation 2, it should be noted that $\langle Q_{sk} \rangle$ corresponds to the ρ_{THE} of the system. A similar shape of the ρ_{THE} is reproduced from the simulation which reveals the underlying physics of the appearance of single or double peaks. Figure 4(a) shows the $\langle Q_{sk} \rangle$ as a function of field. A single peak in $\langle Q_{sk} \rangle$ has been observed for D = 0.5 to 2.5 mJ/m³. Beyond D = 2.5 mJ/m³, double peaks in $\langle Q_{sk} \rangle$ became prominent. As seen, with enhancing D, the maximum value of $\langle Q_{sk} \rangle$ increases, and a transformation from single to double peak in $\langle Q_{sk} \rangle$ occurs. Thus, D is a very important parameter in deciding the nature ρ_{THE} .



Figure 5: (a) A single peak in $\langle Q_{sk} \rangle$ for $D = 2.0 \text{ mJ/m}^2$ and $K_{eff} = 0.4 \text{ MJ/m}^3$ obtained from simulations. The blue arrows refer to the corresponding domain structures as shown in (b-g). The green arrow represents the field sweep direction.

For a single peak in $\langle Q_{sk} \rangle$ (figure 5(a), considering $D = 2 \text{ mJ/m}^2$ and $K_{eff} = 0.4 \text{ MJ/m}^3$), while the field has been reduced from a positive saturation, the reversed domain with $\langle Q_{sk} \rangle$ = 0 is nucleated (see figure 5(b)). Further, by reducing the field the reverse domain expands (figure 5(c)) and is interconnected with neighbouring domains to form a worm-like structure (figure 5(d)). Now, the worm-like domain breaks into skyrmions with $\langle Q_{sk} \rangle = +1$ (figure 5(e)-(g)) with decreasing the field (i.e., increasing the field in -ve direction) and contributing to Hall resistivity. With a very higher field again oppositely saturated FM ground state has been achieved. Thus, it should be noted that the peak in $\langle Q_{sk} \rangle$ or ρ_{THE} comes due to only one type of topological object.

In the case of a double peak, (figure 6(a), considering $D = 5 \text{ mJ/m}^2$ and $K_{eff} = 0.4 \text{ MJ/m}^3$) while decreasing the field, several reverse nuclei occur in terms of chiral domain walls (DW), elongated skyrmions or skyrmions (due to presence of high iDMI) which contribute to $Q_{sk} = -1$. With increasing the field in the reverse direction, the nuclei expand and merge with nearby topological objects and a chiral worm-like domain phase is achieved giving a maximum value $\langle Q_{sk} \rangle = -17$ (figure 6(e)). Further, with the field, the worm phase again breaks into skyrmions with opposite polarity i.e., $Q_{sk} = +1$ (figure 6 (f)), and finally, a state with maximum isolated skyrmion ($\langle Q_{sk} \rangle = +38$) is achieved (figure 6(h)). Therefore, the double peak in $\langle Q_{sk} \rangle$ or ρ_{THE} is formed by the contribution of two topological objects with opposite polarity.



Figure 6: (a) A double peak with opposite sign in $\langle Q_{sk} \rangle$ for $D = 5.0 \text{ mJ/m}^2$ and $K_{eff} = 0.4 \text{ MJ/m}^3$ obtained from simulations. The red arrows refer to the corresponding domain structures as shown in (b-g). The green arrow represents the field sweep direction.

So far, we have investigated the effect of D on $\langle Q_{sk} \rangle$ or ρ_{THE} . However, the anisotropy of the system plays a major role in deciding the minimum energy state which helps to stabilize a chiral texture in a system. Thus, K_{eff} is also varied in the simulation over a range of 0.10.8 MJ/m³ and found that the shape of the $\langle Q_{sk} \rangle$ also depends on it. A phase plot of D vs K_{eff} has been shown in Figure 7. As observed, the shape of $\langle Q_{sk} \rangle$ or ρ_{THE} depends on both the parameter D and K_{eff} and using a proper combination of them, a single to double peak transition in ρ_{THE} can be achieved. From the above discussion, it could be concluded that the existence of relatively low iDMI induces a single peak in ρ_{THE} for the Pt/Co/Ta sample whereas double peaks arise in Pt/Co/Re samples due to the presence of higher iDMI.



Figure 7: (a) A phase plot of D vs K_{eff} which shows the single to double peak transition in $\langle Q_{sk} \rangle$. The red cross mark represents no skyrmion during the field sweep.

Conclusion

In summary, the THE has been observed in both Pt/Co/Ta and Pt/Co/Re systems indicating the existence of skyrmions which is confirmed via MFM. A maximum ρ_{THE} of ~ 0.08 and ~ 0.12 nΩ-m has been observed for sample Pt/Co/Ta and Pt/Co/Re, respectively. Two different natures of topological Hall resistivity are observed in the samples. As seen, the effective anisotropy (K_{eff}) and DMI interaction play a pivotal role in determining THE signal in a system. By choosing a proper combination of K_{eff} and iDMI value (D) of a system, one can achieve single to double peak transition.

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